

74ACQ543• 74ACTQ543

Quiet Series™ Octal Registered Transceiver with 3-STATE Outputs

General Description

The ACQ/ACTQ543 is a non-inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

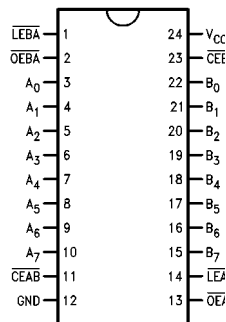
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- 8-bit octal latched transceiver
- Separate controls for data flow in each direction
- Back-to-back registers for storage
- Outputs source/sink 24 mA
- 300 mil slim PDIP/SOIC

Ordering Code:

Order Number	Package Number	Package Description
74ACQ543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACQ543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74ACTQ543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACTQ543QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150 Wide
74ACTQ543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the order code.

Connection Diagram

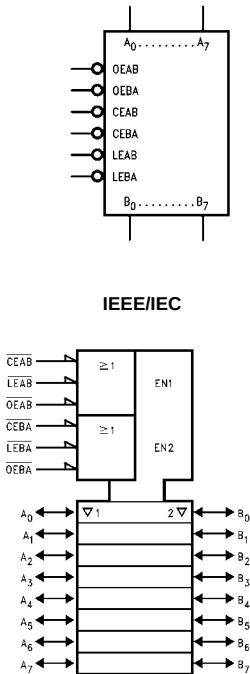


Pin Descriptions

Pin Names	Description
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)
A_0-A_7	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0-B_7	B-to-A Data Inputs or A-to-B 3-STATE Outputs

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Logic Symbols



Functional Description

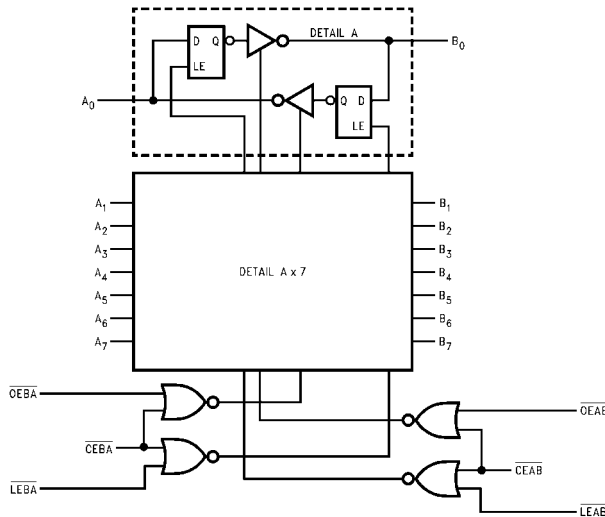
The ACQ/ACTQ543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable (CEAB) input must be LOW in order to enter data from A₀–A₇ or take data from B₀–B₇, as indicated in the Data I/O Control Table. With CEAB LOW, a LOW signal on the A-to-B Latch Enable (LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the CEBA, LEBA and OEBA inputs

Data I/O Control Table

Inputs			Latch Status	Output Buffers
CEAB	LEAB	OEAB		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using CEBA, LEBA and OEBA

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	-20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	-0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	-0.5V to $V_{CC} + 0.5V$
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
DC Latch-up Source or	
Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage V_{CC}	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate $\Delta V/\Delta t$	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V _{CC} (V)	T _A = +25°C		T _A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V _{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V _{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I _{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
		3.0		2.56	2.46	V	V _{IN} = V _{IL} or V _{IH} I _{OH} = −12 mA I _{OH} = −24 mA I _{OH} = −24 mA (Note 2)
		4.5		3.86	3.76		
		5.5		4.86	4.76		
V _{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
		3.0		0.36	0.44	V	V _{IN} = V _{IL} or V _{IH} I _{OL} = 12 mA I _{OL} = 24 mA I _{OL} = 24 mA (Note 2)
		4.5		0.36	0.44		
		5.5		0.36	0.44		
I _{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V _I = V _{CC} , GND
I _{OLD}	Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 3)	5.5			−75	mA	V _{OHD} = 3.85V Min
I _{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V _{IN} = V _{CC} or GND
I _{OZT}	Maximum I/O Leakage Current	5.5		± 0.6	± 6.0	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V _{CC} (V)	T _A = +25°C		T _A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.1	1.5		V	Figures 1, 2 (Note 5)(Note 6)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	−0.6	−1.2		V	Figures 1, 2 (Note 5)(Note 6)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: Plastic DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n-1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V _{CC} (V)	T _A = +25°C		T _A = -40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		5.5	1.5	2.0	2.0		
V _{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		5.5	1.5	0.8	0.8		
V _{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I _{OUT} = -50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	V _{IN} = V _{IL} or V _{IH} I _{OH} = -24 mA I _{OH} = -24 mA (Note 8)
		5.5		4.86	4.76		
V _{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	V _{IN} = V _{IL} or V _{IH} I _{OL} = 24 mA I _{OL} = 24 mA (Note 8)
		5.5		0.36	0.44		
I _{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V _I = V _{CC} , GND
I _{OZT}	Maximum I/O Leakage Current	5.5		±0.6	6.0	μA	V _(OE) = V _{IL} , V _{IH} V _O = V _{CC} , GND
I _{CCT}	Maximum I _{CC} /Input	5.5	0.6		1.5	mA	V _I = V _{CC} - 2.1V
I _{OLD}	Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 9)	5.5			-75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V _{IN} = V _{CC} or GND
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.1	1.5		V	Figures 1, 2 (Note 10)(Note 11)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.6	-1.2		V	Figures 1, 2 (Note 10)(Note 11)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package

Note 11: Max number of outputs defined as (n). (n-1) Data Inputs are driven 0V to 3V, one output @ GND.

Note 12: Max number of Data Inputs (n) switching. (n-1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for AC

Symbol	Parameter	V _{CC} (V) (Note 13)	T _A = +25°C C _L = 50 pF			T _A = −40°C to +85°C C _L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t _{PLH}	Propagation Delay	3.3	1.5	8.0	11.0	1.5	11.5	ns
t _{PHL}	Transparent Mode A _n to B _n or B _n to A _n	5.0	1.5	5.0	7.0	1.5	7.5	
t _{PLH}	Propagation Delay	3.3	1.5	9.0	12.5	1.5	13.0	ns
t _{PHL}	LEBA, LEAB to A _n , B _n	5.0	1.5	6.0	8.0	1.5	8.5	
t _{PZH}	Output Enable Time	3.3	1.5	10.5	15.0	1.5	15.5	ns
t _{PZL}	OEBA or OEAB to A _n or B _n CEBA or CEAB to A _n or B _n							
t _{PHZ}	Output Disable Time	3.3	1.0	8.0	11.0	1.0	11.5	ns
t _{PLZ}	OEBA or OEAB to A _n or B _n CEBA or CEAB to A _n or B _n							
t _{OSHL}	Output to Output	3.3	1.0			1.5		ns
t _{OSLH}	Skew (Note 14)	5.0	0.5			1.0		

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for AC

Symbol	Parameter	V _{CC} (V) (Note 15)	T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF		Units
			Typ	Guaranteed Minimum			
t _S	Setup Time, HIGH or LOW	3.3		3.0	3.0	ns	
	A _n or B _n to LEBA or LEAB	5.0					
t _H	Hold Time, HIGH or LOW	3.3		1.5	1.5	ns	
	A _n or B _n to LEBA or LEAB	5.0					
t _W	Latch Enable	3.3		4.0	4.0	ns	
	Pulse Width, LOW	5.0					

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.0V ± 0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V _{CC} (V) (Note 16)	T _A = +25°C C _L = 50 pF			T _A = -40°C to +85°C C _L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay Transparent Mode A _n to B _n or B _n to A _n	5.0	1.5	5.5	7.5	1.5	8.0	ns
t _{PLH} t _{PHL}	Propagation Delay $\overline{\text{LEBA}}$, $\overline{\text{LEAB}}$ to A _n , B _n	5.0	1.5	6.5	8.5	1.5	9.0	ns
t _{PZH} t _{PZL}	Output Enable Time $\overline{\text{OEBA}}$ or $\overline{\text{OEAB}}$ to A _n or B _n CEBA or CEAB to A _n or B _n	5.0	1.5	8.0	10.0	1.5	10.5	ns
t _{PHZ} t _{PLZ}	Output Disable Time $\overline{\text{OEBA}}$ or $\overline{\text{OEAB}}$ to A _n or B _n CEBA or CEAB to A _n or B _n	5.0	1.0	5.5	7.5	1.0	8.0	ns
t _{OSHL} t _{OSLH}	Output to Output Skew (Note 17)	5.0		0.5	1.0		1.0	ns

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACTQ

Symbol	Parameter	V _{CC} (V) (Note 18)	T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF		Units
			Typ	Guaranteed Minimum			
t _S	Setup Time, HIGH or LOW A _n or B _n to <u>LEBA</u> or <u>LEAB</u>	5.0		3.0	3.0		ns
t _S	Hold Time, HIGH or LOW A _n or B _n to <u>LEBA</u> or <u>LEAB</u>	5.0		1.5	1.5		ns
t _W	Latch Enable Pulse Width, LOW	5.0		4.0	4.0		ns

Note 18: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	70.0	pF	V _{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator
PC-163A Test Fixture
Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

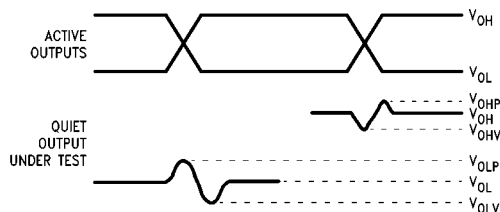


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 19: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: $f = 1$ MHz, $t_r = 3$ ns, $t_f = 3$ ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV} :

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD} :

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL} , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD} .
- Next decrease the input HIGH voltage level, V_{IH} , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD} .
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

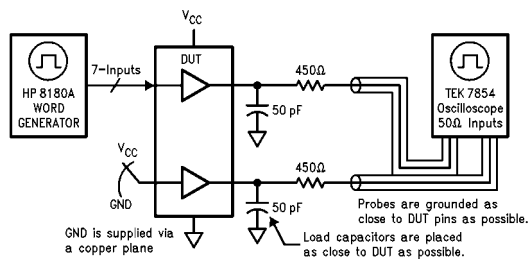


FIGURE 2. Simultaneous Switching Test Circuit

